**JPI Group of Colleges Faisalabad**

**Time: 30 mint *Jinnah College of Science ,Commerce & Technology* Marks:20**

**Subject Name: Electronics 1 Paper: (Objective)**

**Note: Encircle the correct Answer. Use of lead pencil, over cutting and rewriting are not allowed**

1. An atom consists of
2. One nucleus and only one electron c)One nucleus and one or more electrons
3. Protons, electrons, and neutrons
4. Valence electrons are
5. In the closest orbit to the nucleus c) In the most distant orbit from the nucleus
6. In various orbits around nucleus d) Not associated with a particular atom
7. The most widely used semiconductive material in electronic devices is
8. Germanium (b)Carbon (c)Copper (d)Silicon
9. The current in a semiconductor is produced by
10. Electrons only b)Holes only c)Negative ions

d)Both electrons and holes

1. The process of adding an impurity to an intrinsic semiconductor is called
2. Dopping b)Recombination c)Atomic modification d)Ionization
3. A pn junction is formed by
4. The recombination of electrons and holes
5. Ionization
6. The boundary of a p-type and an n-type material
7. The collision of a proton and a neutron
8. The depletion region is created by
9. Ionization (b) Diffusion c) Recombination d) a&b&c
10. The term bias means
11. The ratio of majority carrier to minority carriers
12. The amount of current across a diode
13. A Dc voltage is applied to control the operation of a device
14. Neither a,b or c
15. The depletion region consists of
16. Nothing but minority carrier c) Positive and negative ions
17. No majority carriers d) Answer (b) and (c)
18. When a diode is forward bias
19. The only current is hole current
20. The only current is electron current
21. The only current is produced by majority carrriers
22. The current is produced by both holes and electrons
23. Although current is blocked in reverse bias,
24. There is some current due to majority carriers
25. There is a very small current due to minority carriers
26. There is an avalanche current
27. For a silicon diode, the value of the forward bias voltage typically
28. Must be greater than 0.3V
29. Must be greater than 0.7V
30. Depends on the width of the depletion region
31. Depends on the concentration of majority carriers
32. When forward baised, a diode
33. Blocks currents b)Conducts current c) Has a high resistance d) Drops a large voltage
34. When a voltmeter is placed across a forward biased diode, it will read a voltage approximately equal to
35. The bias battery voltage c) 0V
36. The diode barrier potential d) The total circuit voltage
37. The positive lead of an ohmmeter is connected to the anode of a diode and the negative lead is connected to the cathode. The diode is
38. Reversed biased b)Open c)Forward biased d)Fautly
39. the average value of a half wave rectified voltage with a peak value of 200V is
40. 63.7 V (b)127.3 V (c)141 V (d)0 V
41. When a 60 Hz sinusoidal voltage is applied to the input of a full wave rectifier, the output frequency is
42. 120 Hz (b)60 Hz (c)240 Hz (d)0 Hz
43. The total secondary voltage in a center tapped full wave rectifier is 125 V. neglecting the diode drop, the output voltage is
44. 125 V (b)177 V (c)100 V (d)62.5 V
45. The ideal dc output voltage of a capacitor input filter is equal to
46. The peak value of the rectified voltage
47. The average value of the rectified voltage
48. The rms value of the rectified voltage
49. If the load resistance of a capacitor filtered full wave rectifier is reduced, the ripple voltage
50. Increases b)Decreases c) Is not affected d) Has a different frequency

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**Time: 1:30hrs *Jinnah College of Science ,Commerce & Technology* Marks:30**

**Subject Name: Electronics 1 Paper: (Subjective)**

Question # 2

1. Determine the forward voltage and forward current for the diode in figure (a) for each of the diode models. Also find the voltage across the limiting resistors in each case. Assume r`d=10Ω at the determined value of forward current.
2. Determine the reverse voltage and reverse current for the diode in figure (b) for each of the diode models. Also find the voltage across the limiting resistor in each case. Assume Ir=1µA.

Question # 3

Determine the ripple factor for the filtered bridge rectifier with a load as indicated in figure.

Question # 4

1. What would you expect to see displayed on an oscilloscope connected across RL in the limiter shown.

1. Describe the output voltage waveform for the diode limiter in figure below.

